

PHYSICAL REVIEW LETTERS **124**, 117701 (2020)

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## Resonantly Driven Singlet-Triplet Spin Qubit in Silicon

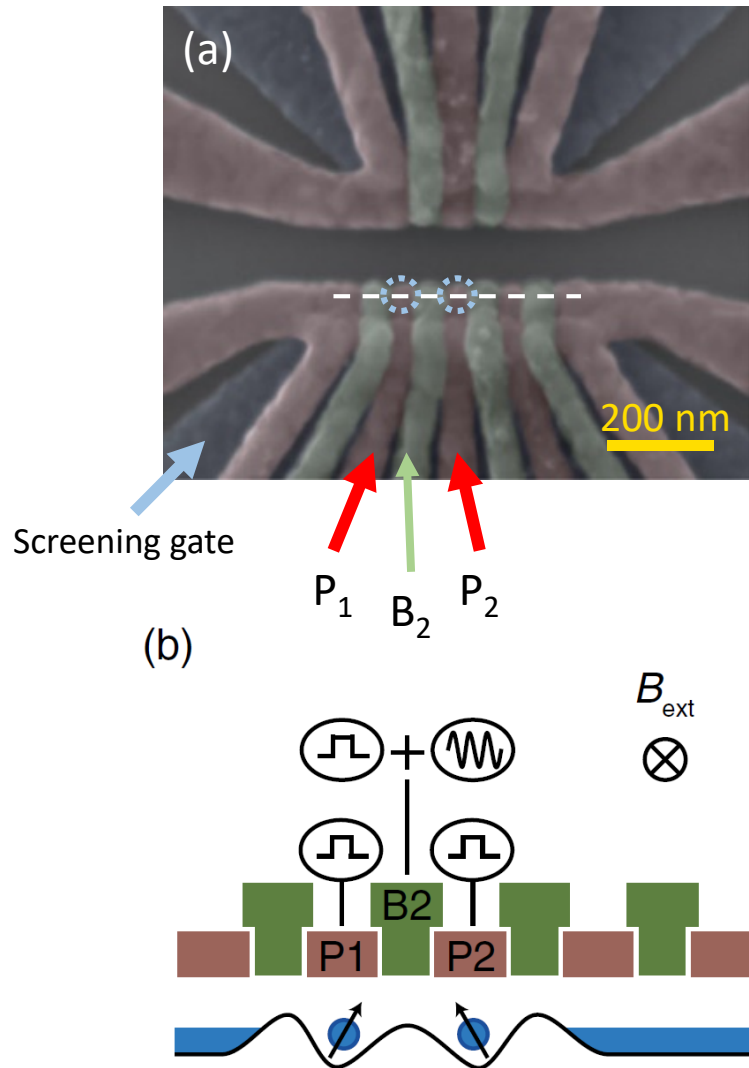
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*Center for Emergent Matter Science (CEMS), RIKEN, Wako-shi, Saitama 351-0198, Japan*

Pierre Chevalier Kwon

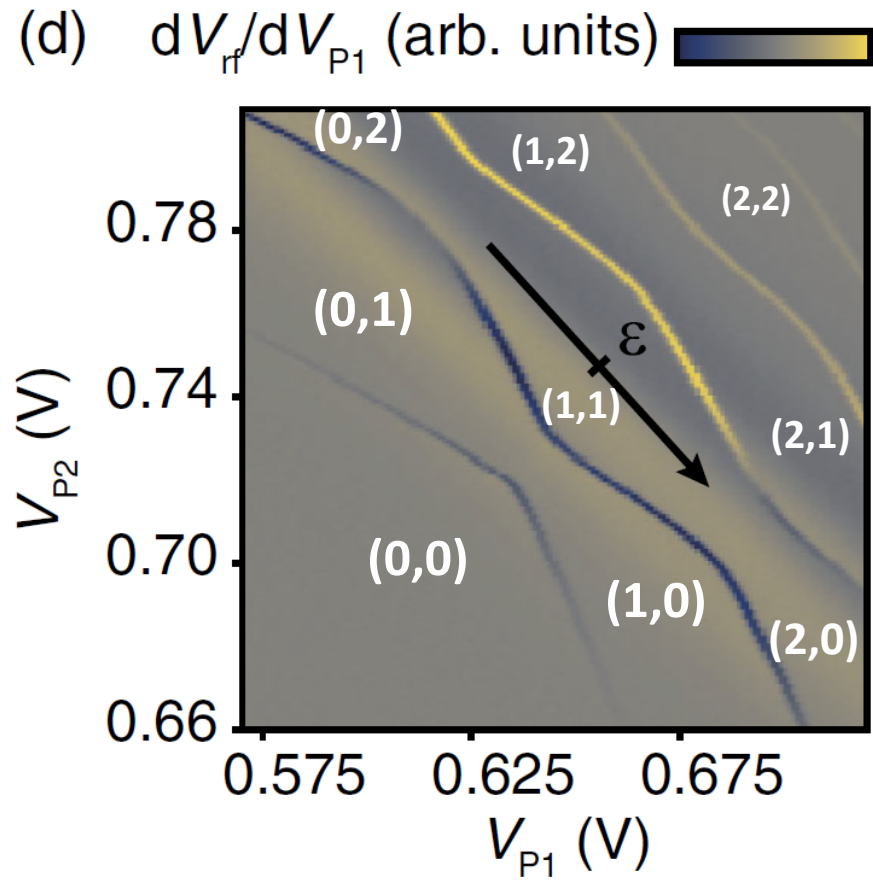
24.04.2020

# Device architecture

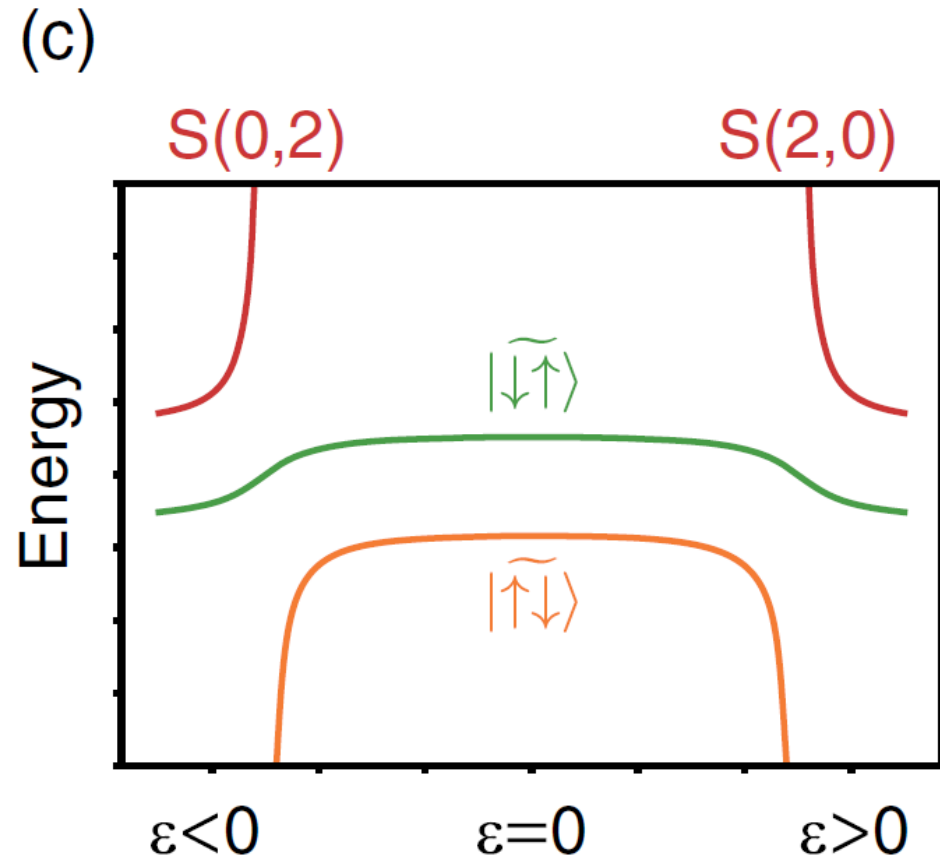
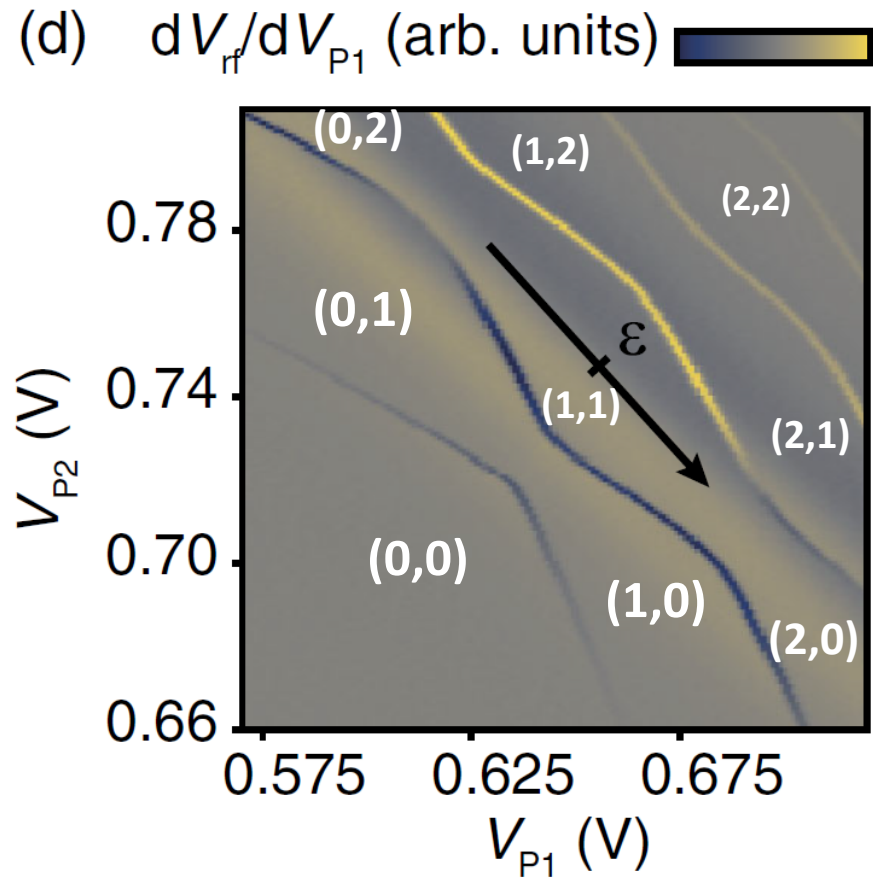


- Si/SiGe heterostructure (2DEG)
- 3 Al layers
- Dilution refrigerator:  $T_e \sim 40$  mK
- Inplane magnetic field:  $B_{ext} \sim 0.5$  T + a “large” magnetic field gradient (in and outplane)
- (Radio-frequency) Sensor QD (at top)
- Coherent driving of the qubit by modulating the exchange interaction ( $\lesssim 1$  GHz)

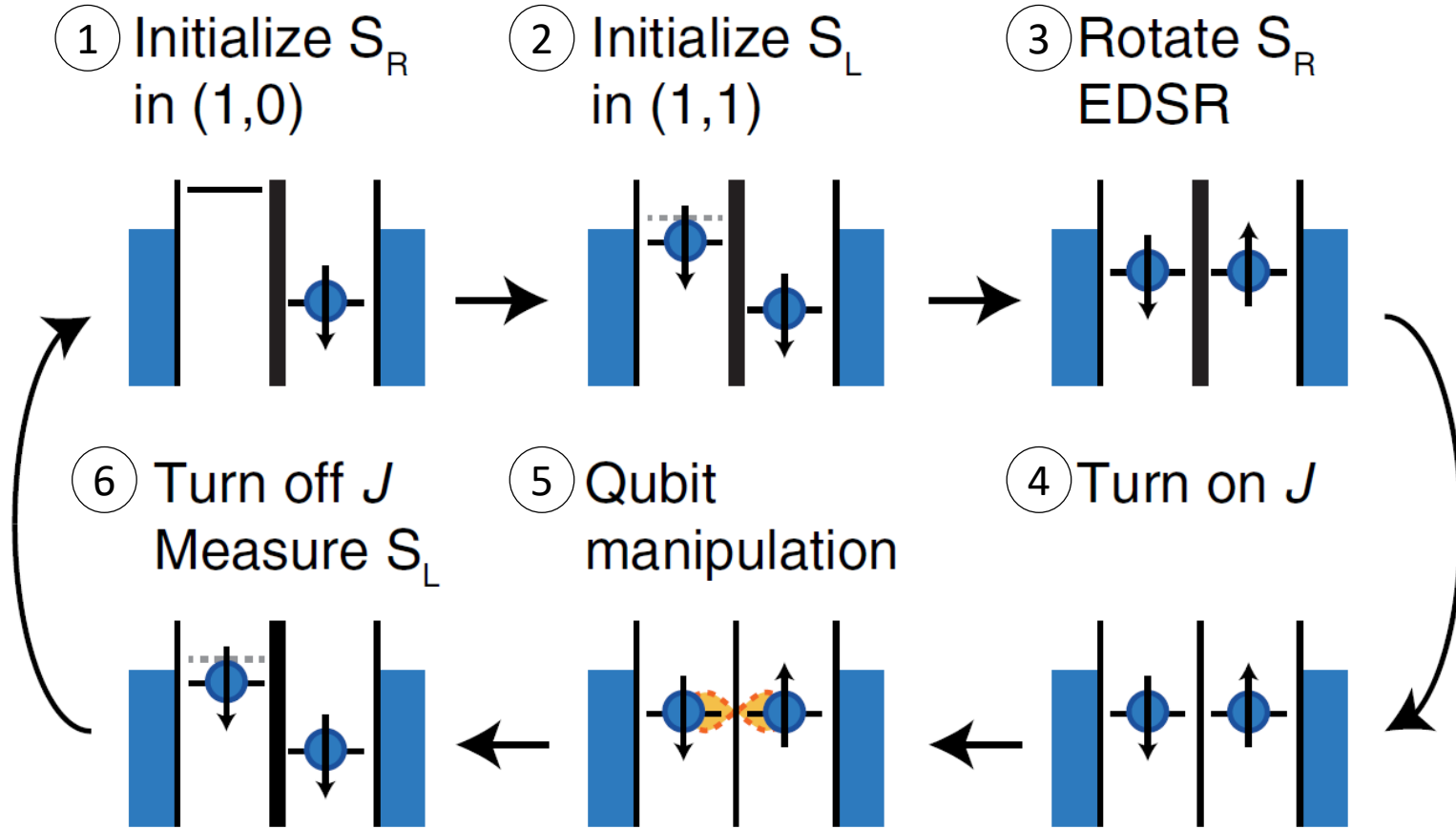
# Charge stability diagram



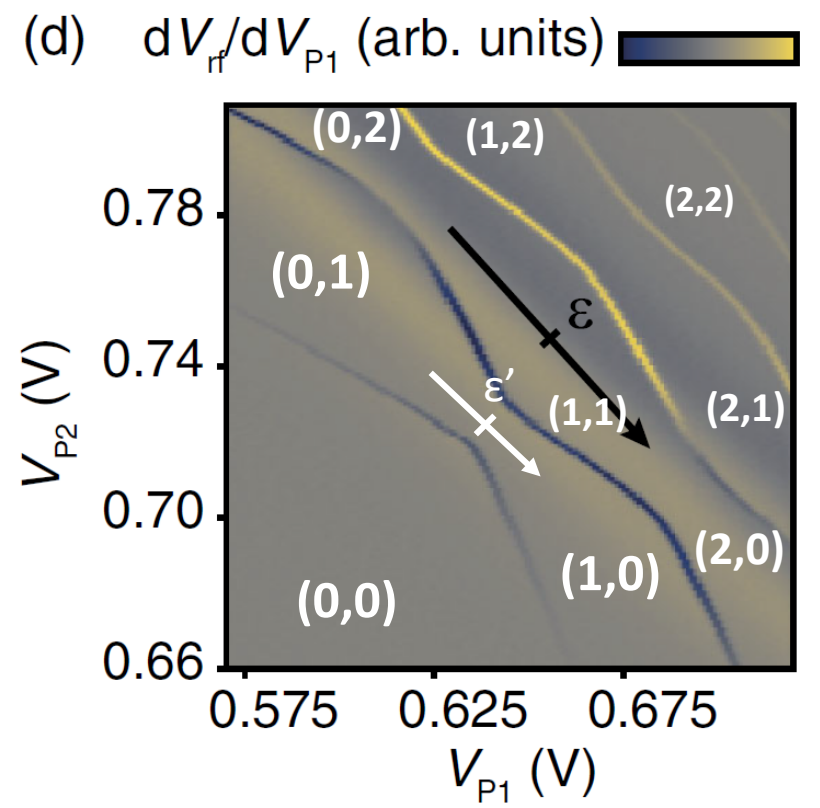
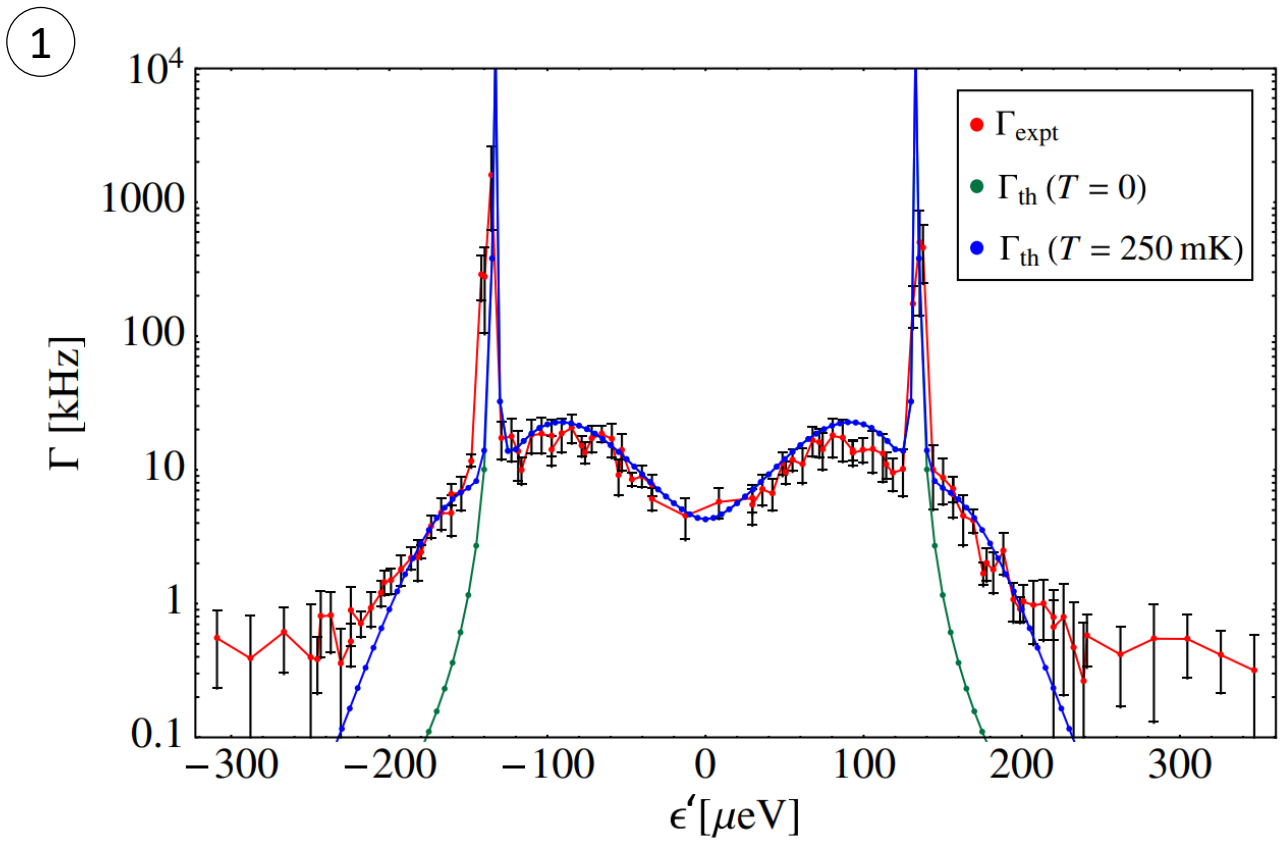
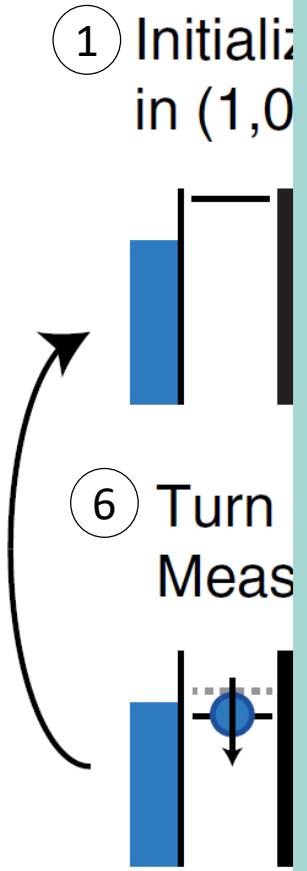
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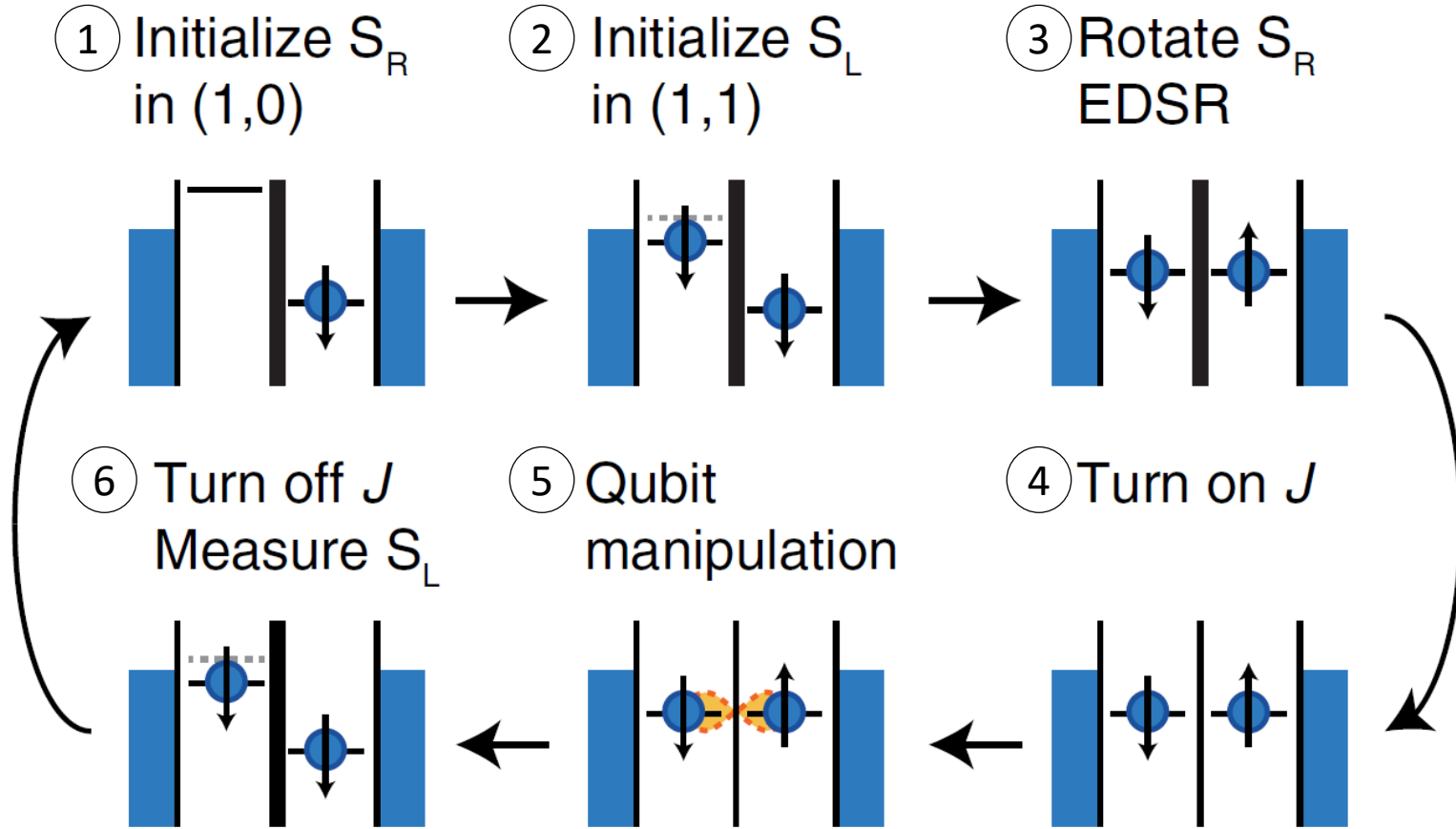
# Measurement sequence: Basic operations



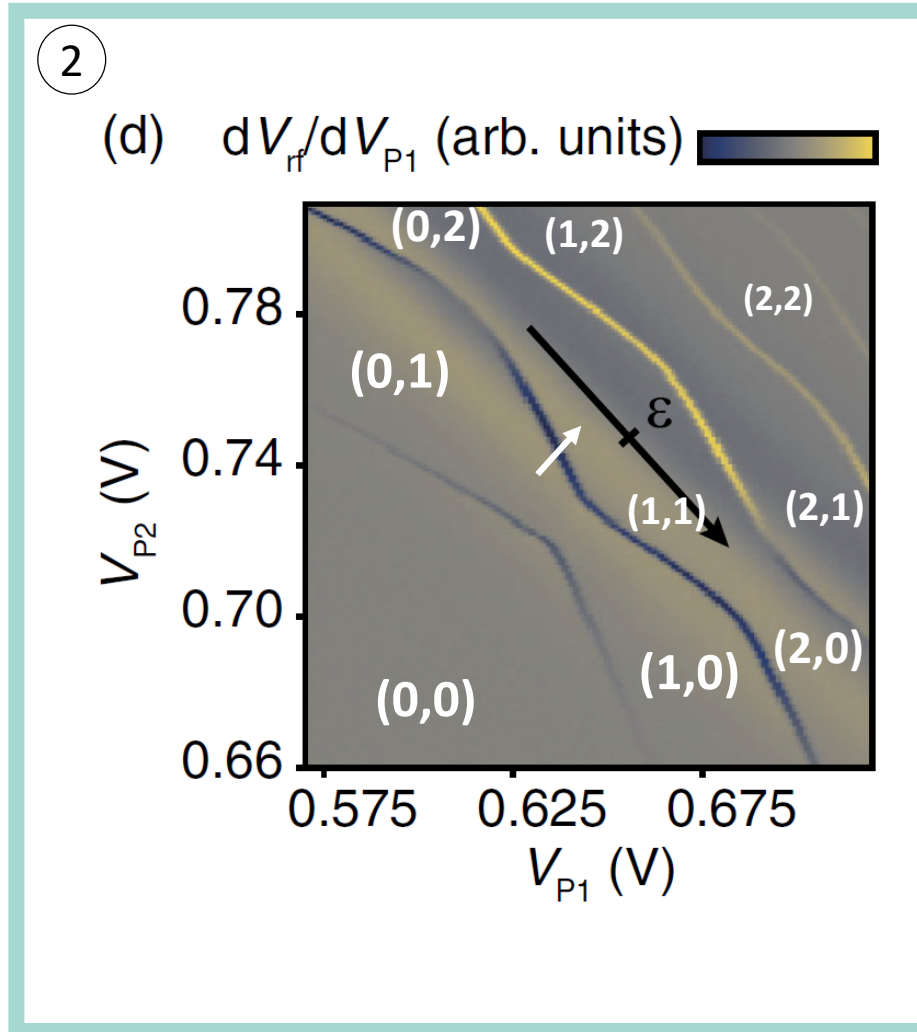
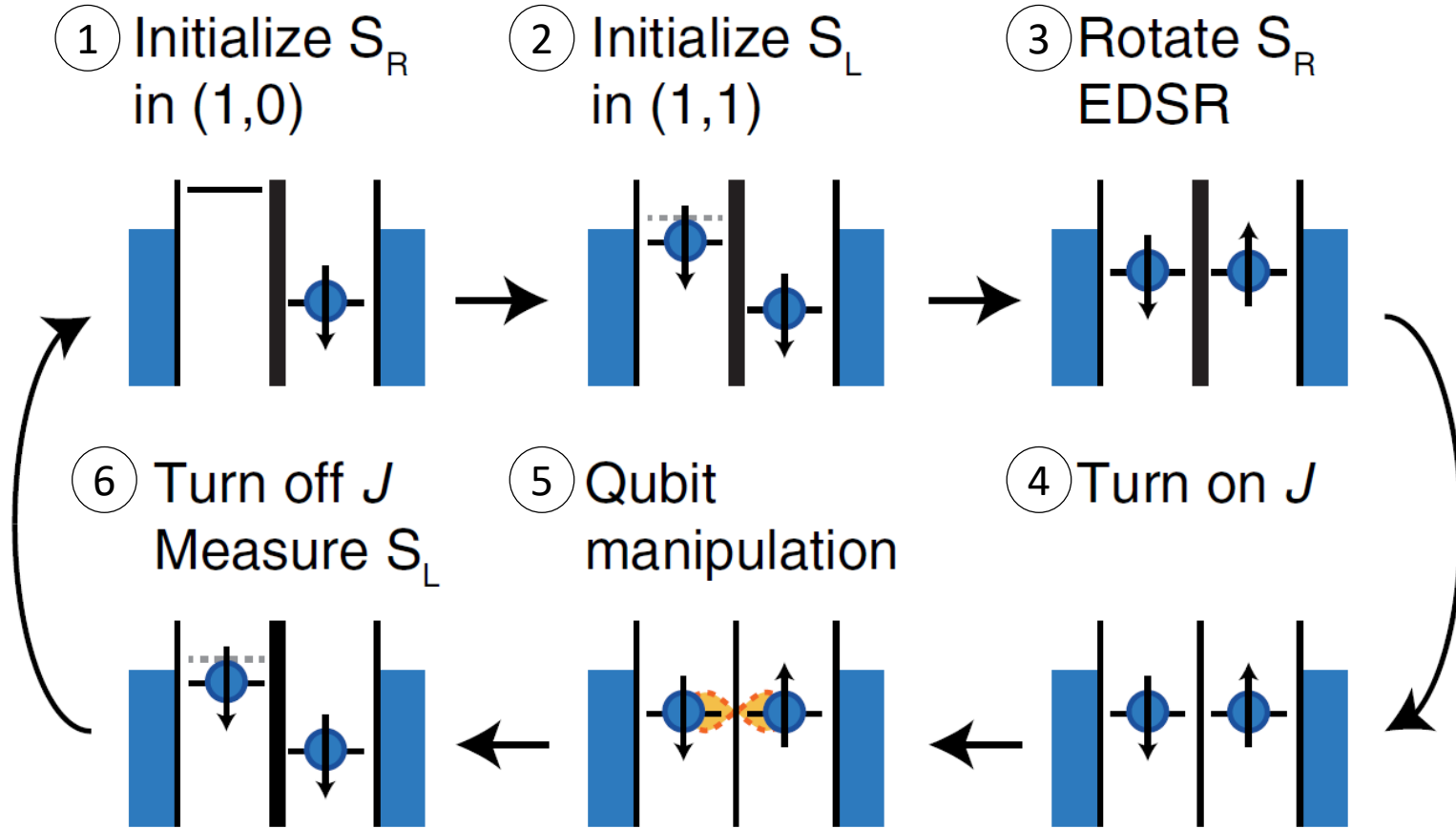
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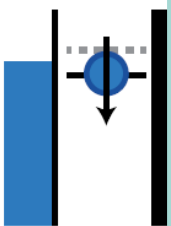


# Measurement sequence: Basic operations

① Initialize  
in  $(1,0)$



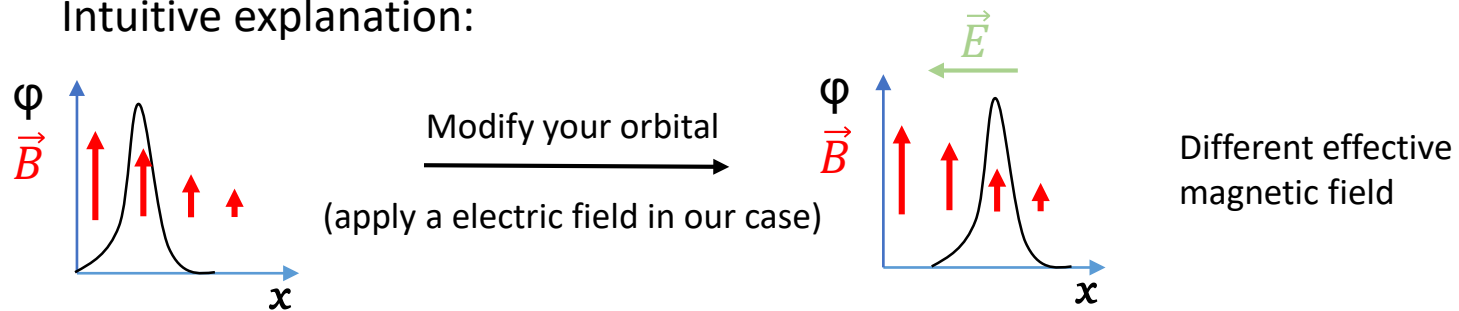
⑥ Turn  
Meas



③ Electric-Dipole Spin Resonance (EDSR)

- Gradient of  $B$  outplane ( $B_{\text{outplane}}$ ) is used to couple electron's spin and orbital degrees of freedom (in other words: allows the ESR)

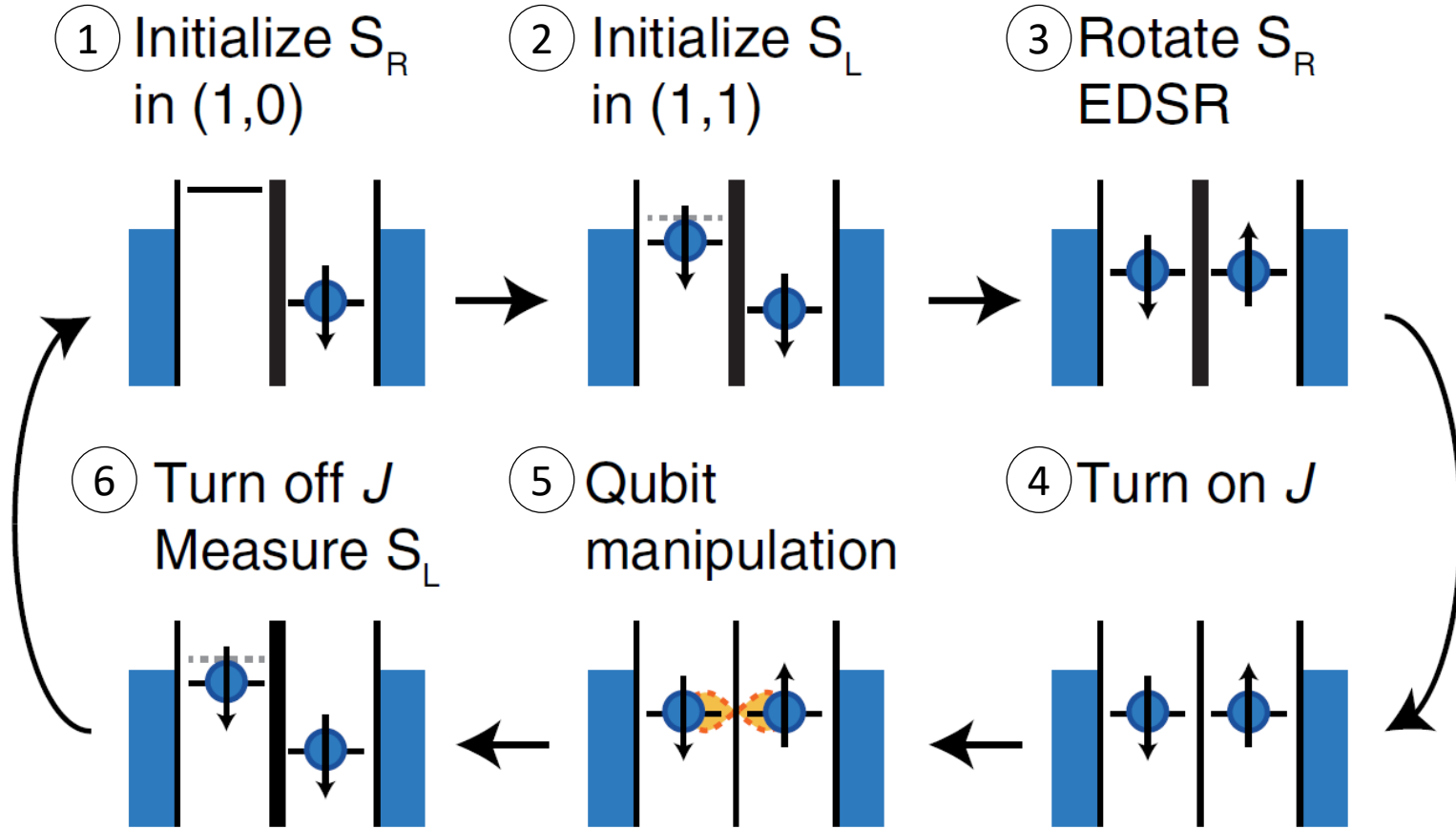
Intuitive explanation:



- Gradient inplane is used to give different Larmor frequencies for spin in each QD. Hence, we can selectively rotate  $S_R$  or  $S_L$  (resonant frequency  $\propto B_{\text{inplane}}$ )
- Typical values\*:  $\delta B_{\text{outplane}} > 0.8 \text{ mT/nm}$  and  $\Delta B_{\text{inplane}} > 18 \text{ mT}$

\*Yasuhiro Tokura, Wilfred G. van der Wiel, Toshiaki Obata, and Seigo Tarucha, Phys. Rev. Lett. 96, 047202 (2006).

# Measurement sequence: Basic operations

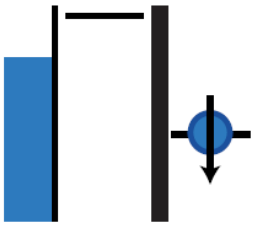


④

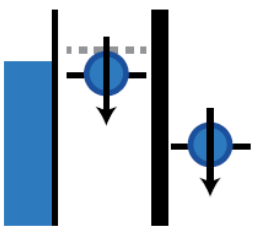
- Square pulse on B2 with  $\delta V_{B_2} = 70$  mV
- Then, the 2 QDs interact

# Measurement sequence: Basic operations

① Initialize S in (1,0)

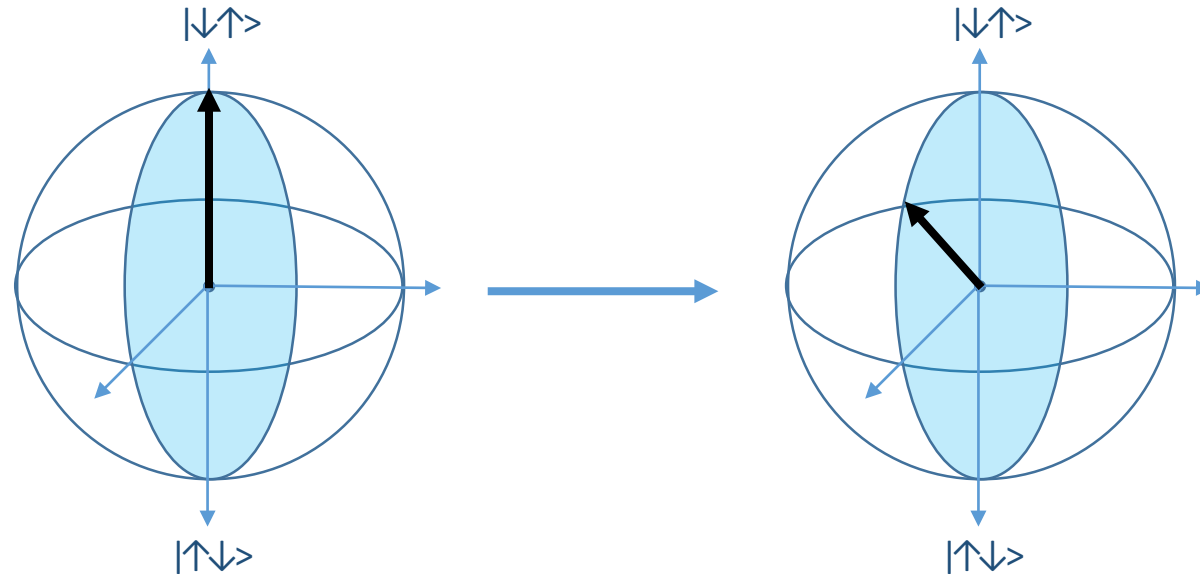


⑥ Turn off Measurement

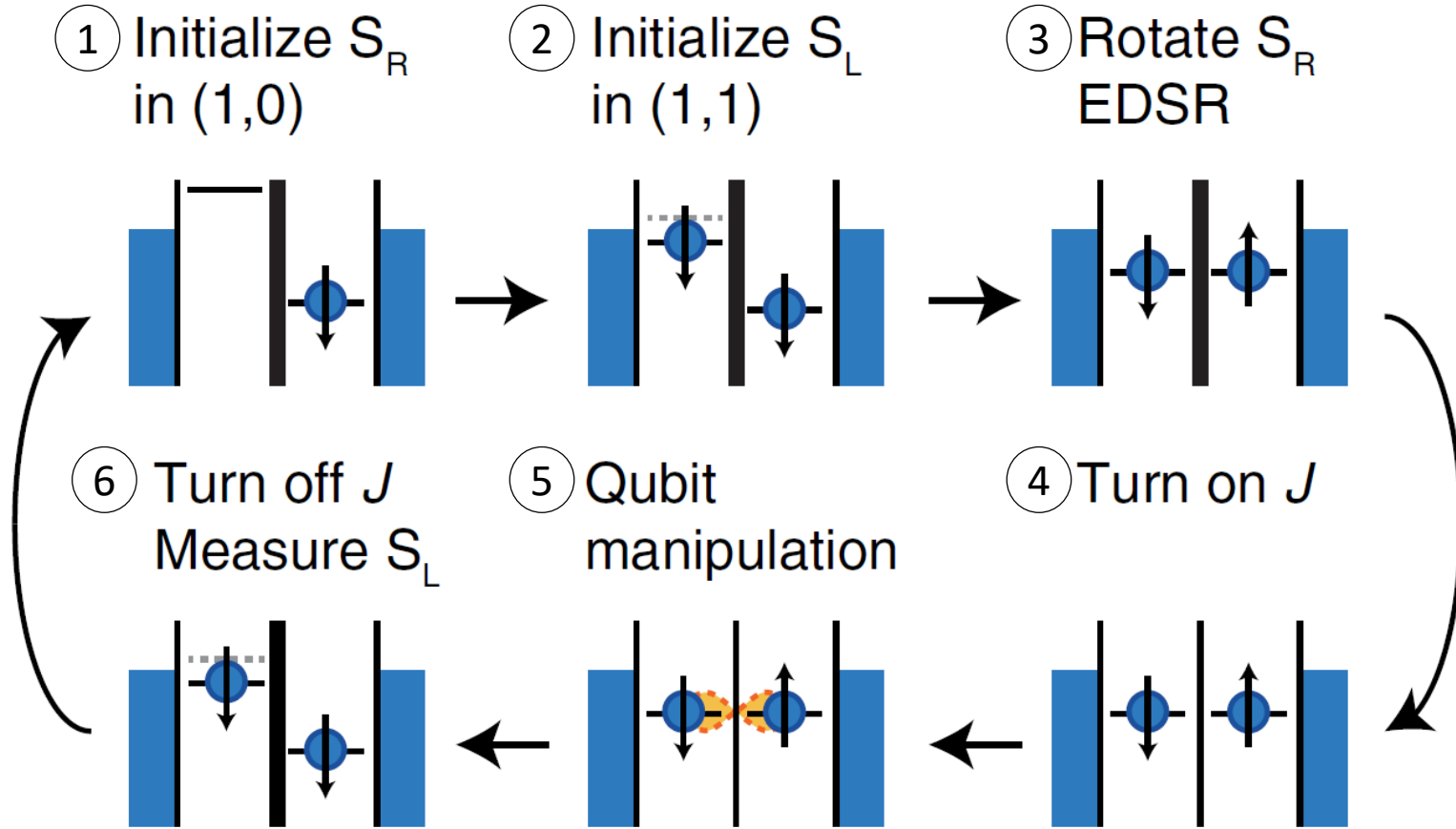


⑤

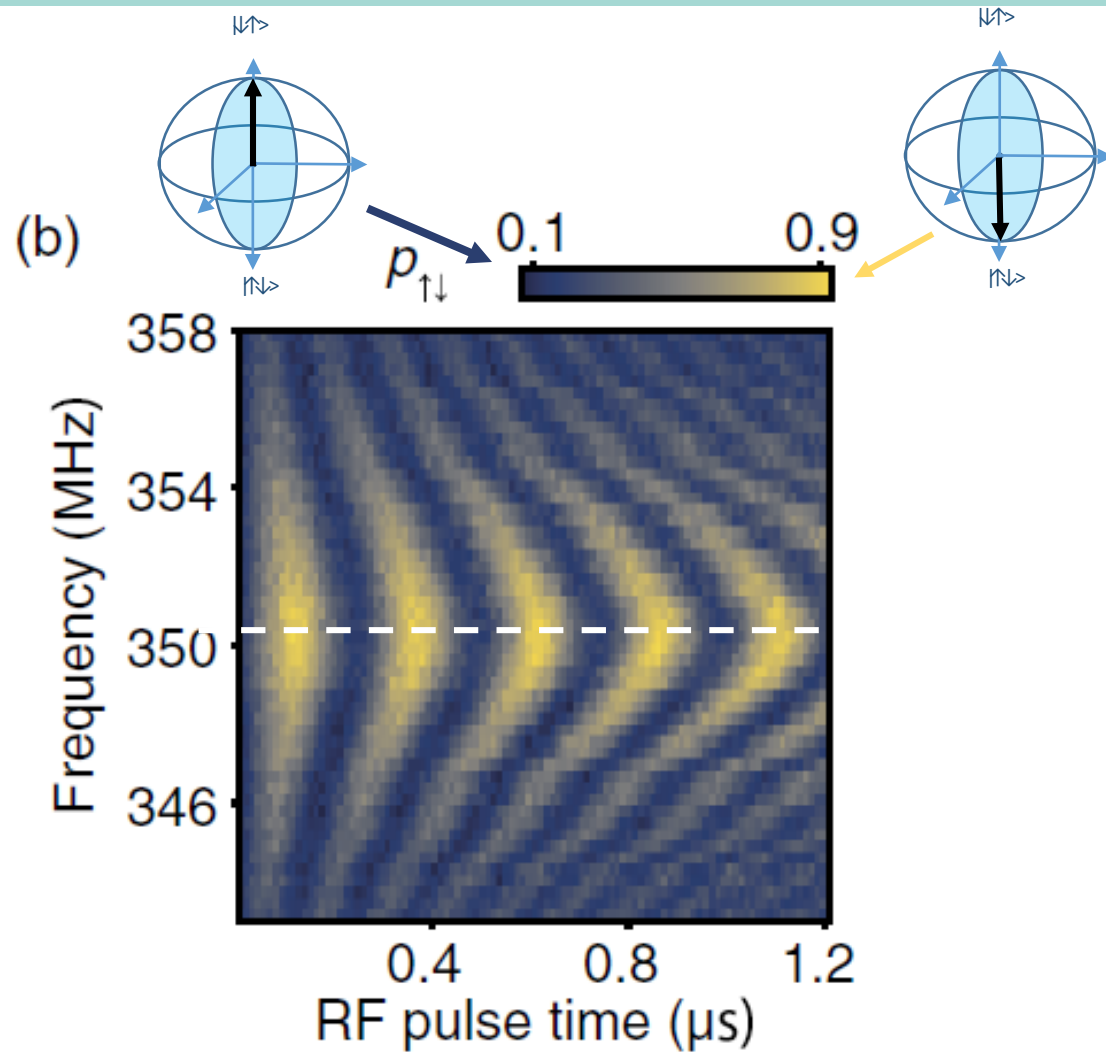
- ac voltage pulses to the B2 gate
- That induce a rotation in our Bloch sphere



# Measurement sequence: Basic operations

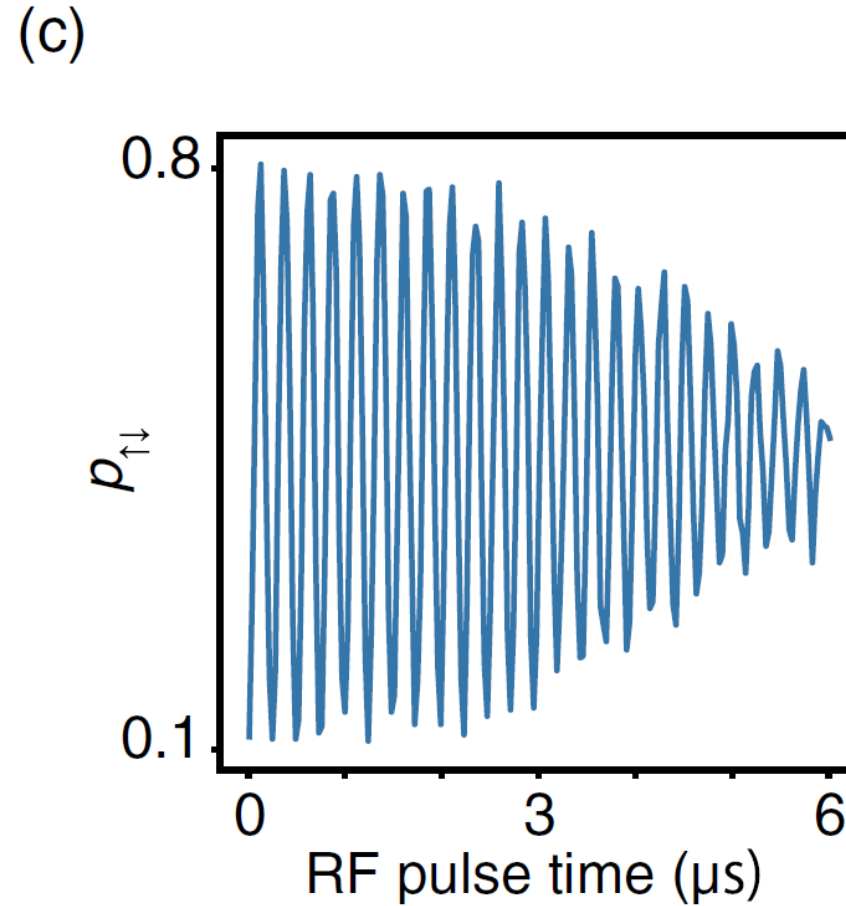
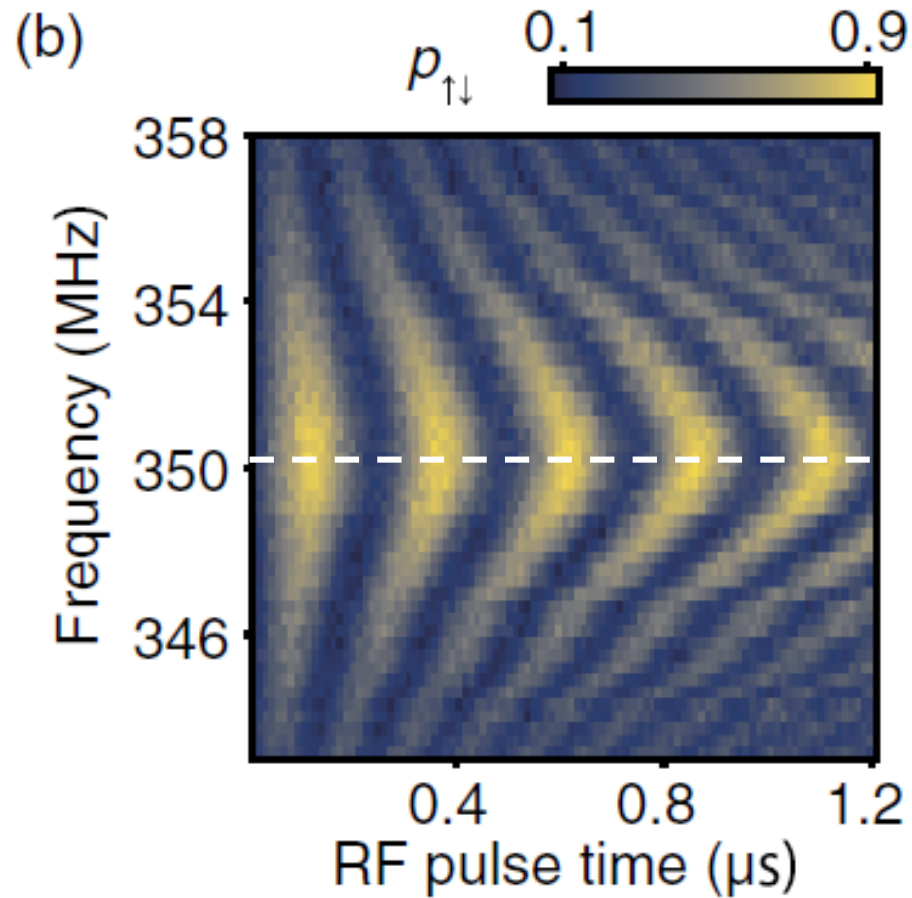


# Rabi chevron oscillations



- ac pulse amplitude (on B2) of 6.3 mV
- Qubit resonance frequency = 351 MHz

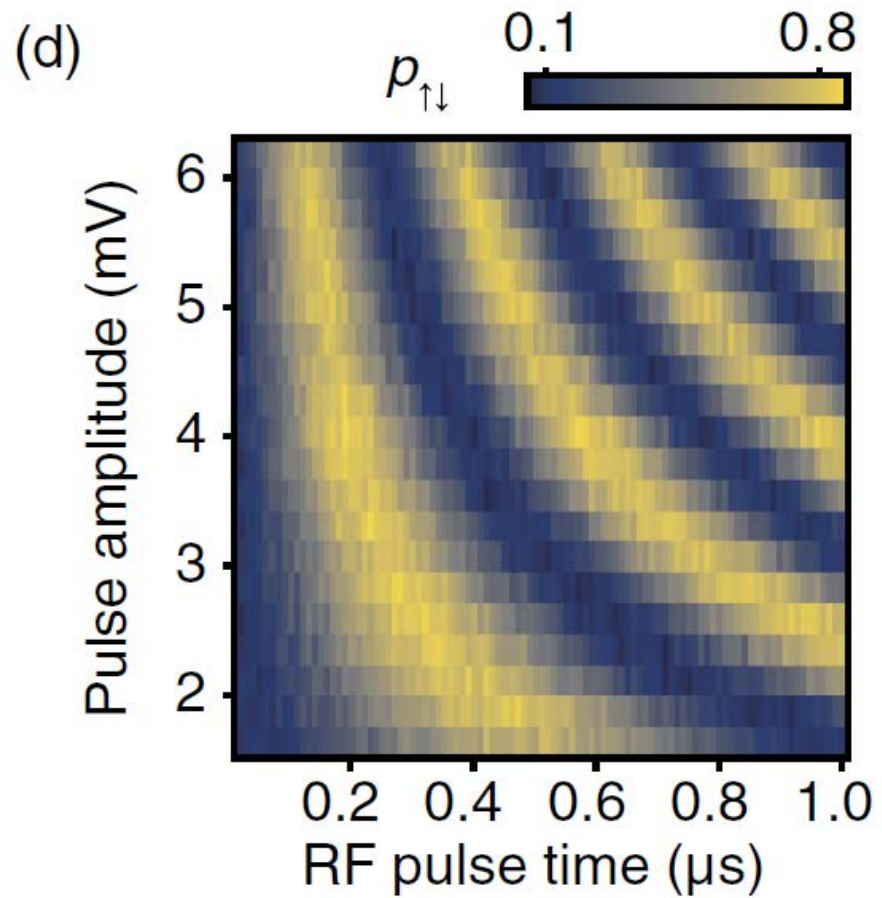
# Rabi chevron oscillations



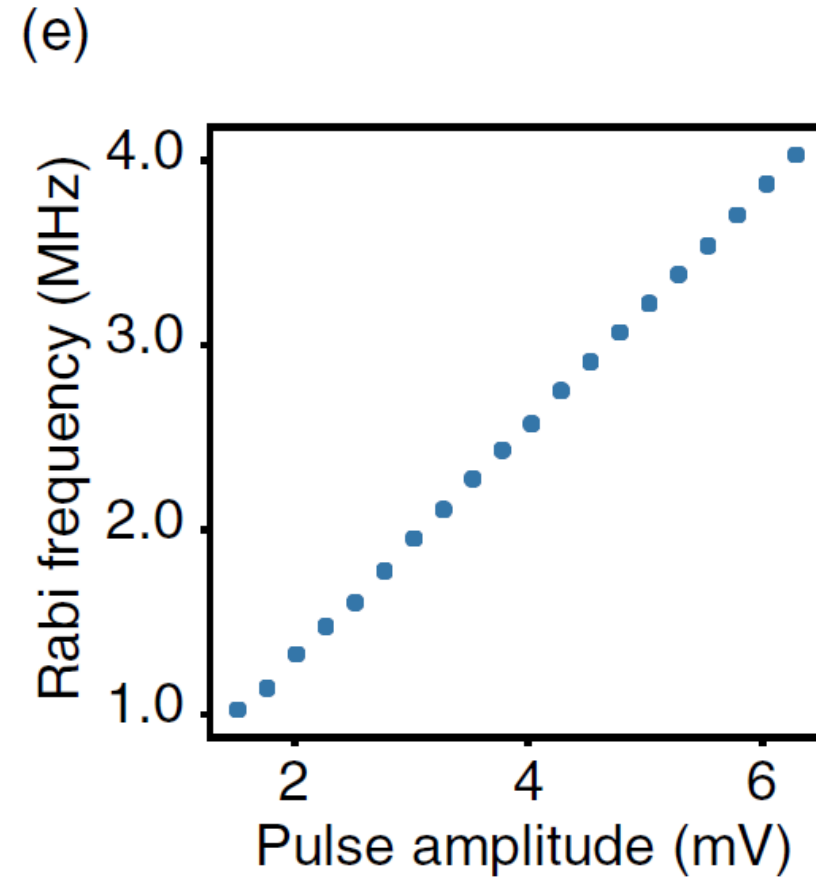
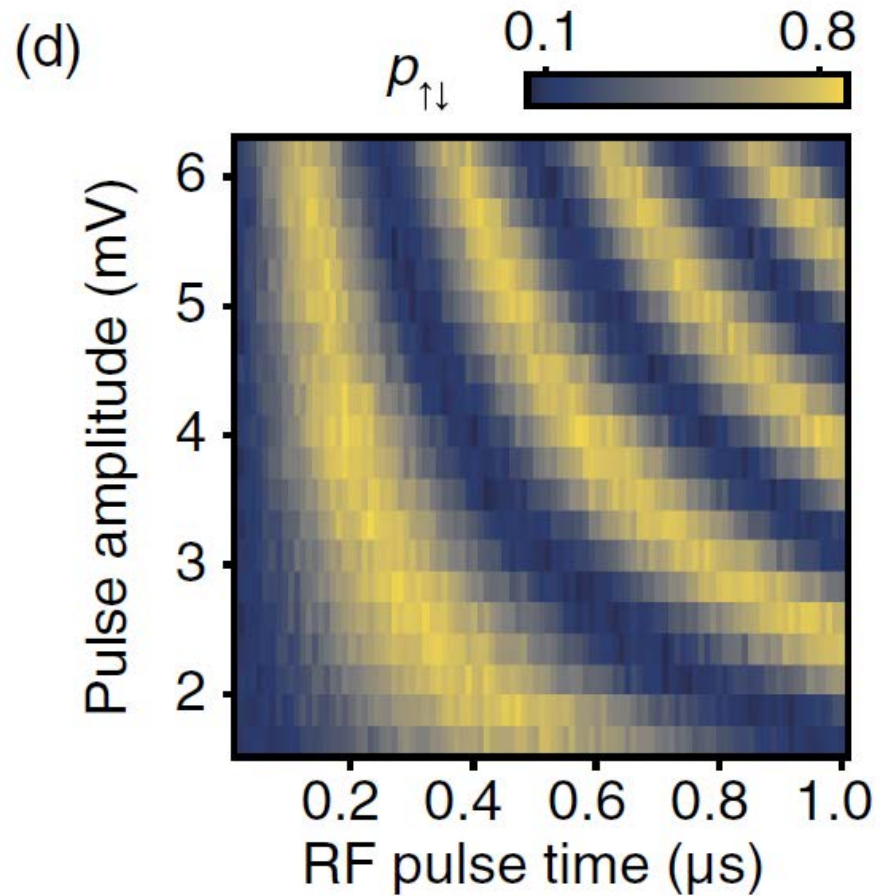
- ac pulse amplitude (on B2) of 6.3 mV
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Rabi oscillation decay time  $T_R \sim 6 \mu\text{s}$

# Amplitude dependence of the Rabi oscillations



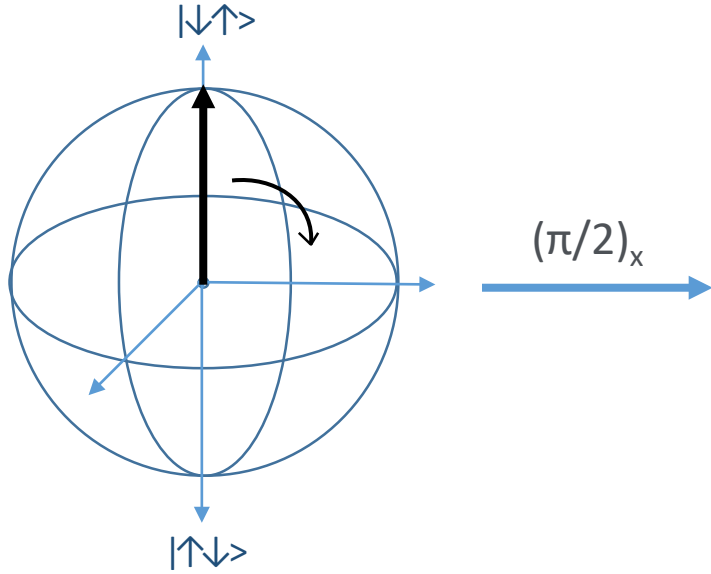
# Amplitude dependence of the Rabi oscillations



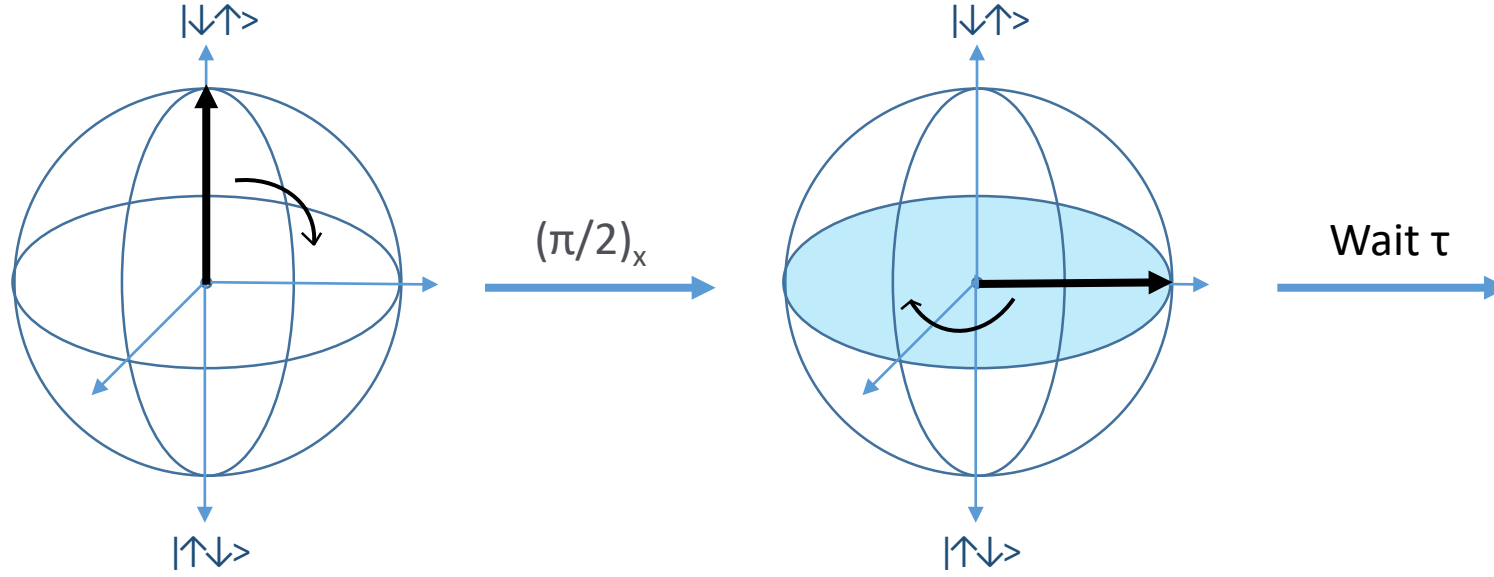
Linear  $\Rightarrow$  The qubit is in the regime where  $J$  changes linearly with  $\delta V_{B_2}$



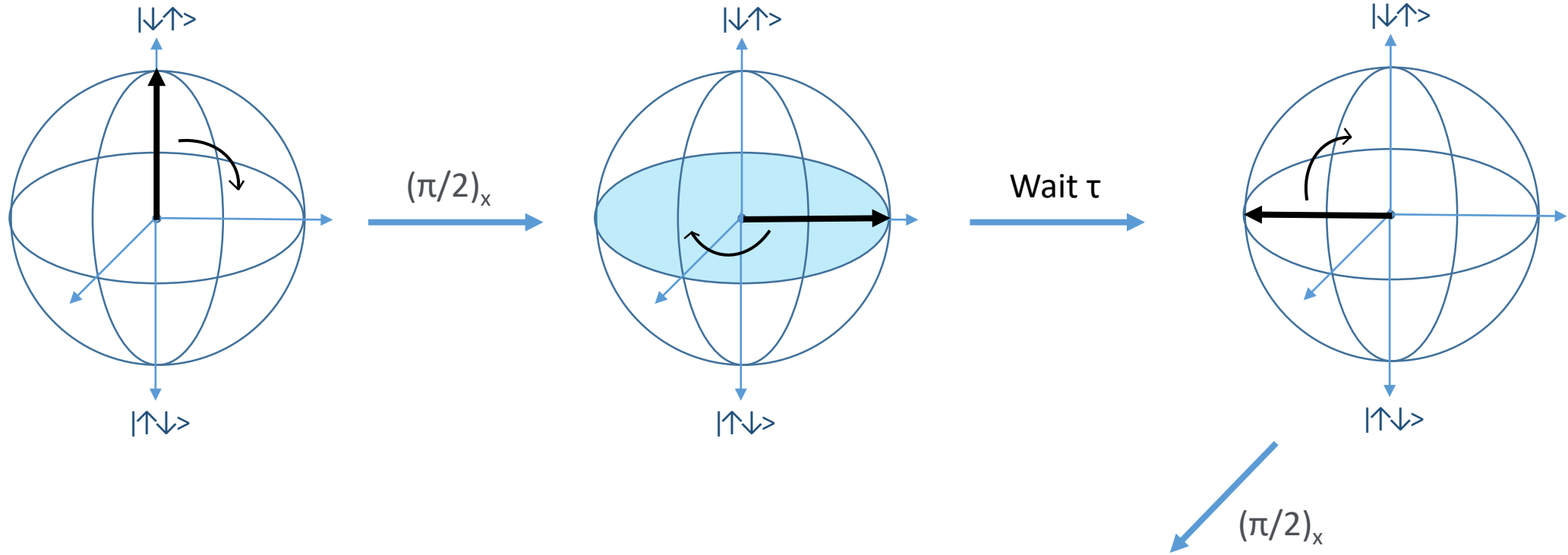
# Ramsey interferometry: Principle



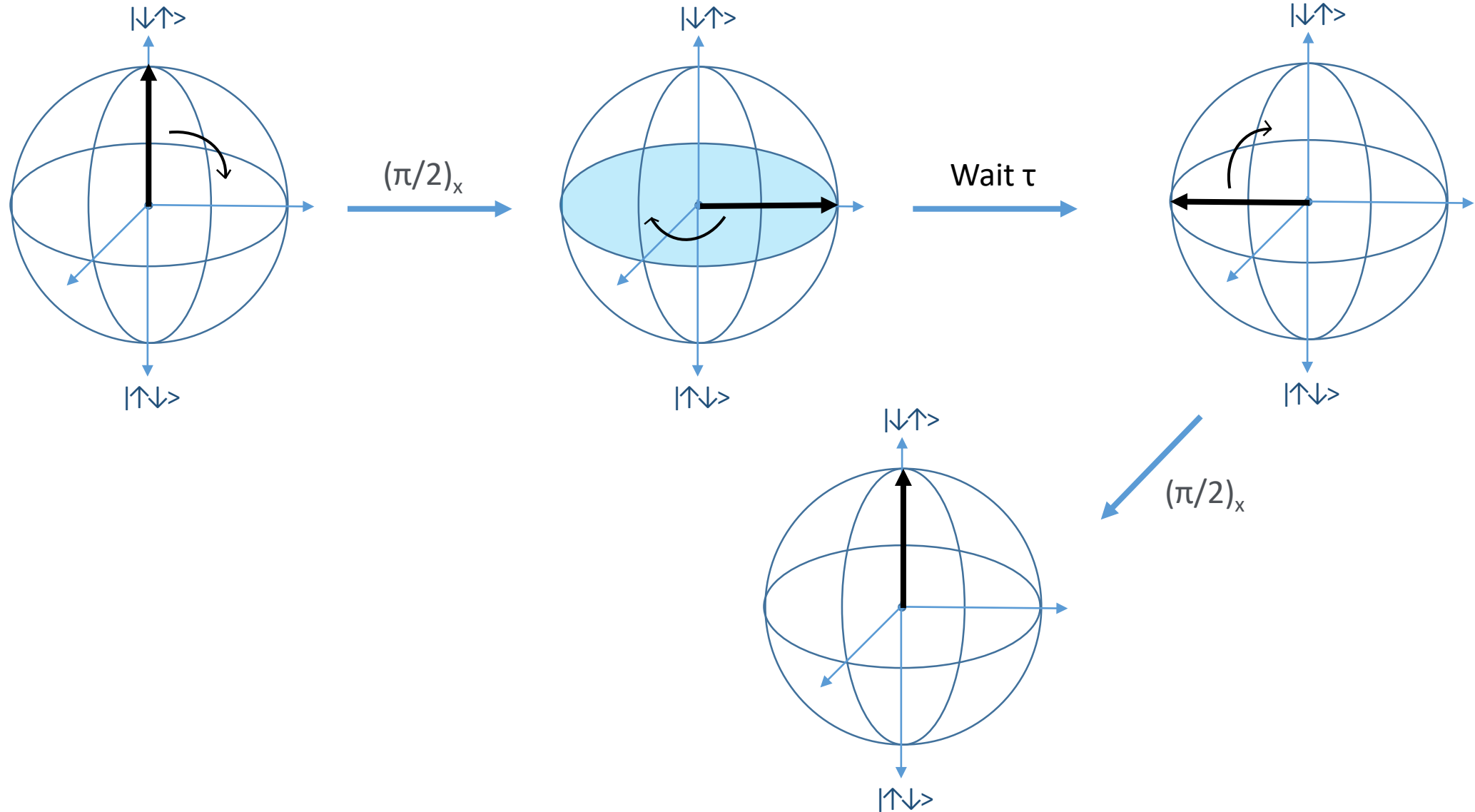
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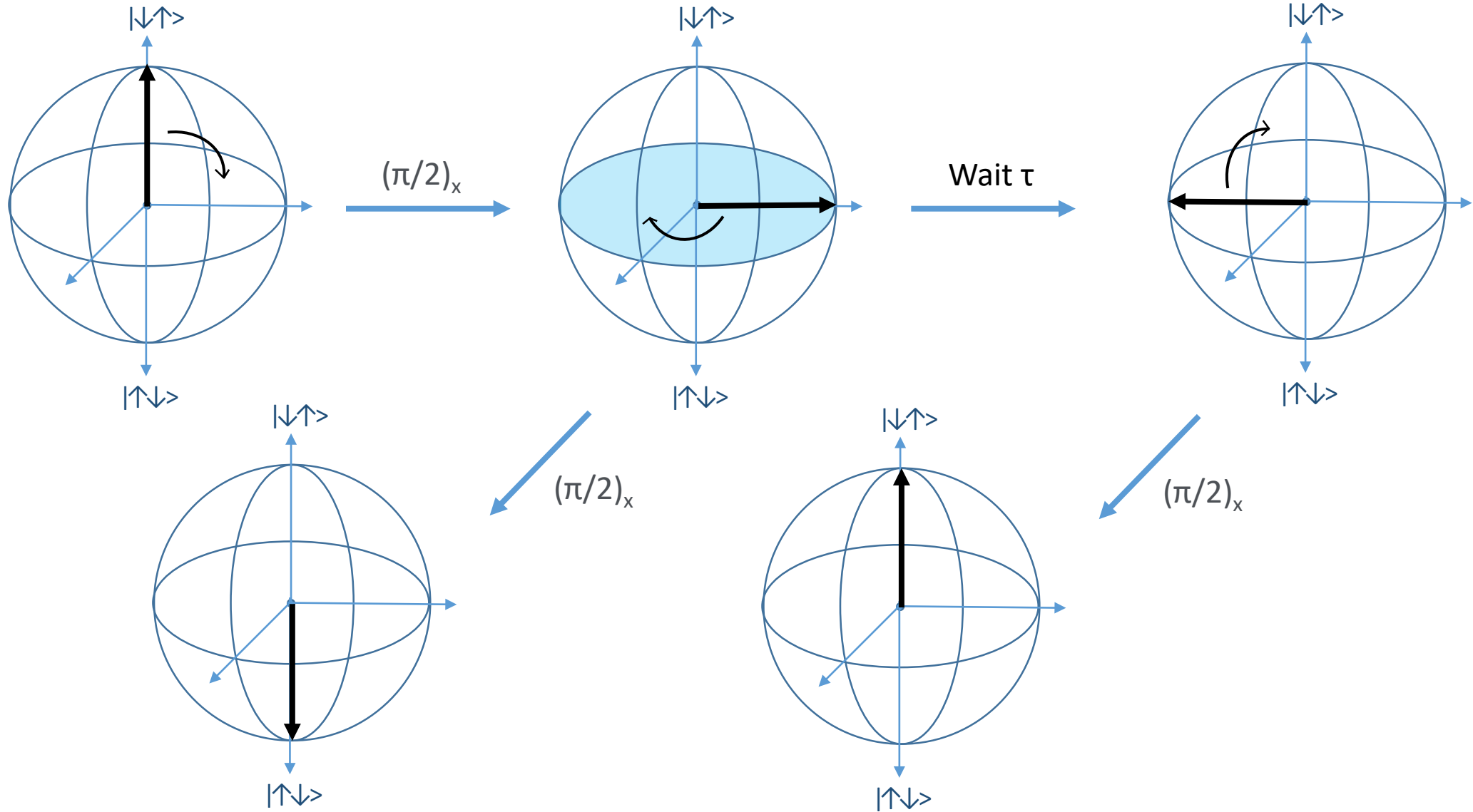
# Ramsey interferometry: Principle



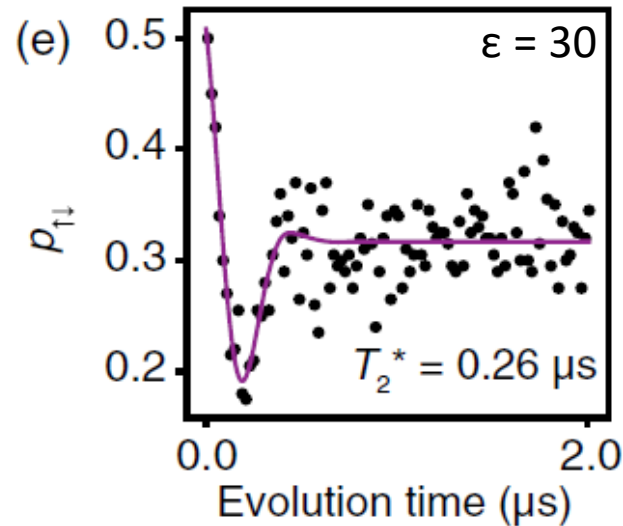
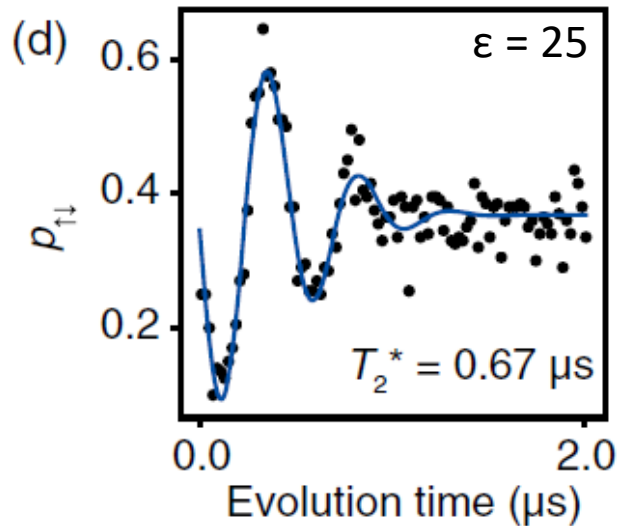
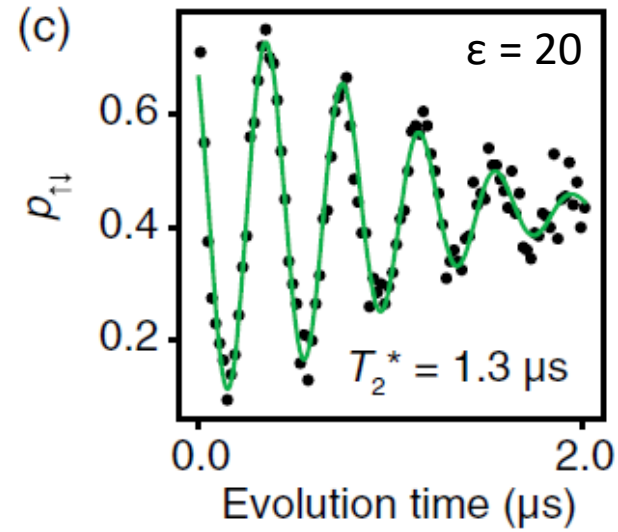
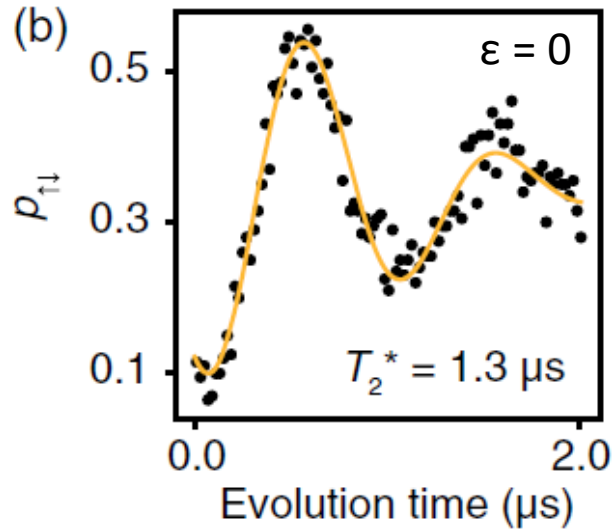
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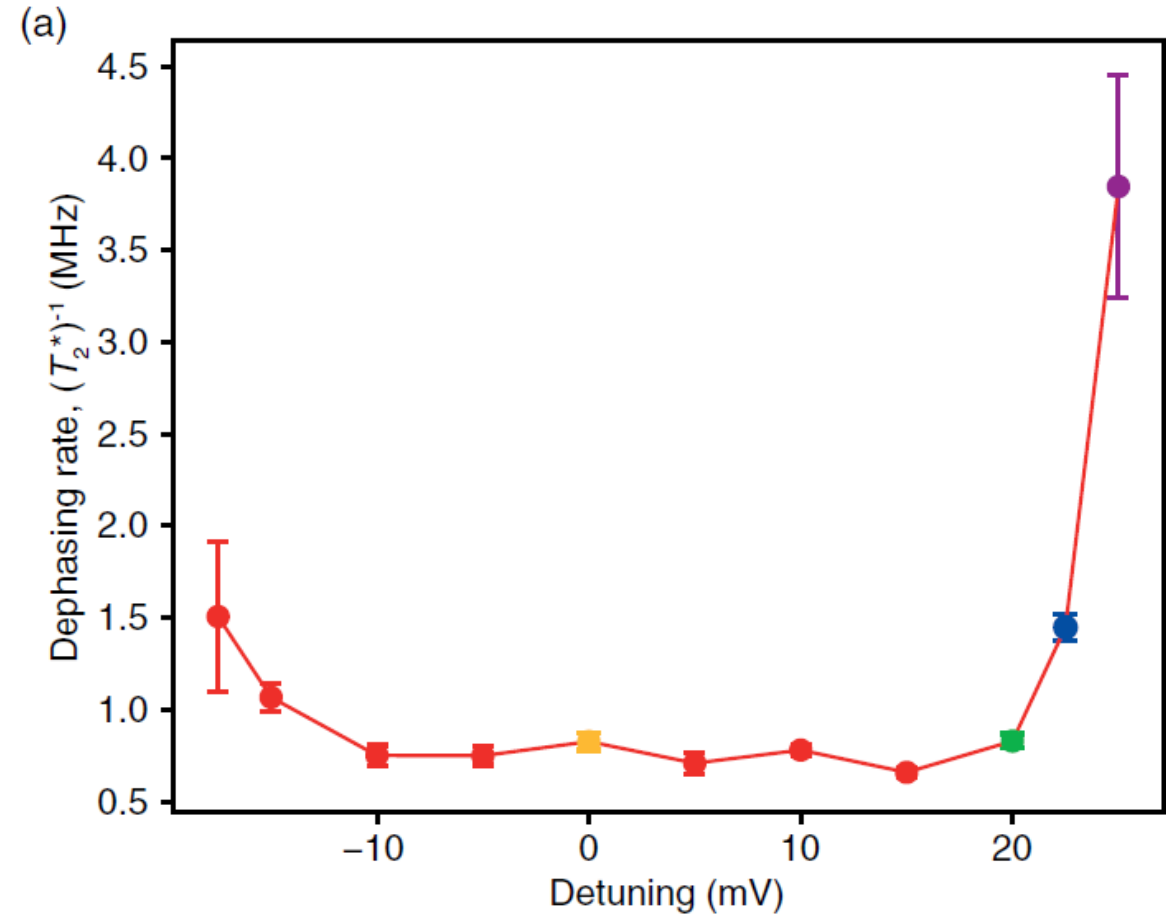
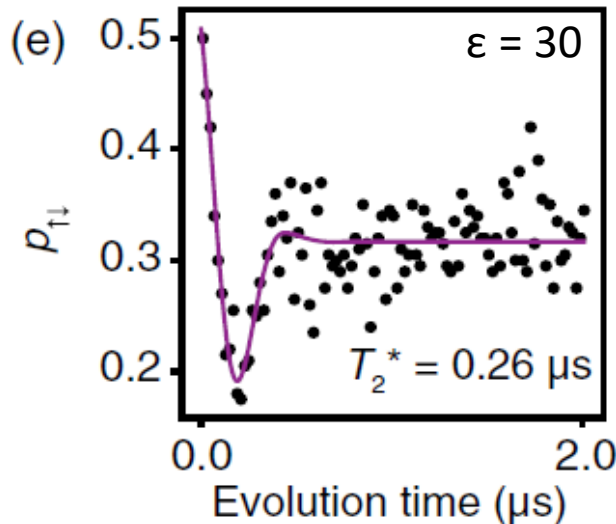
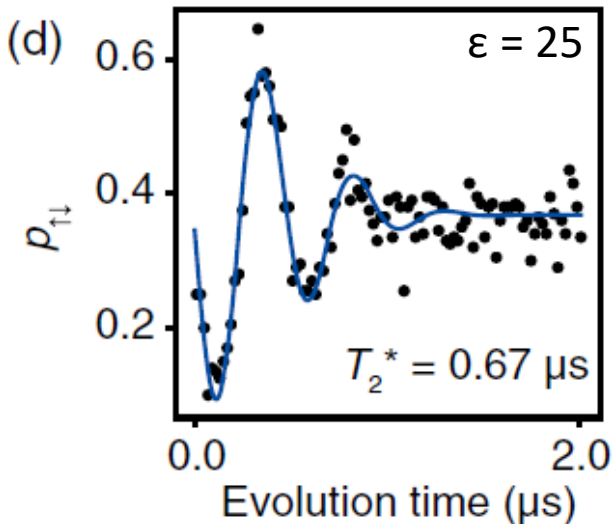
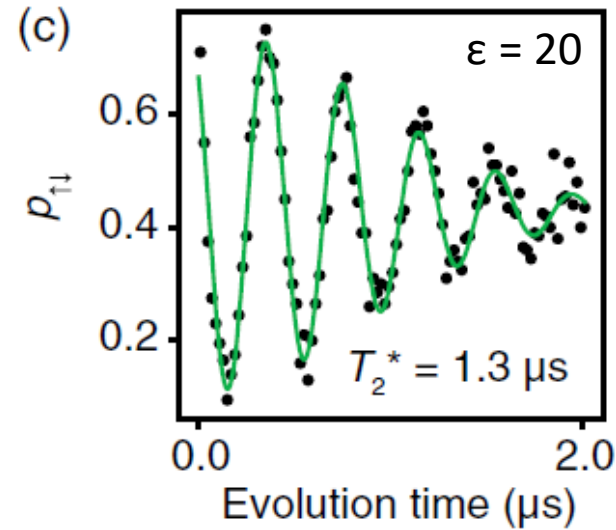
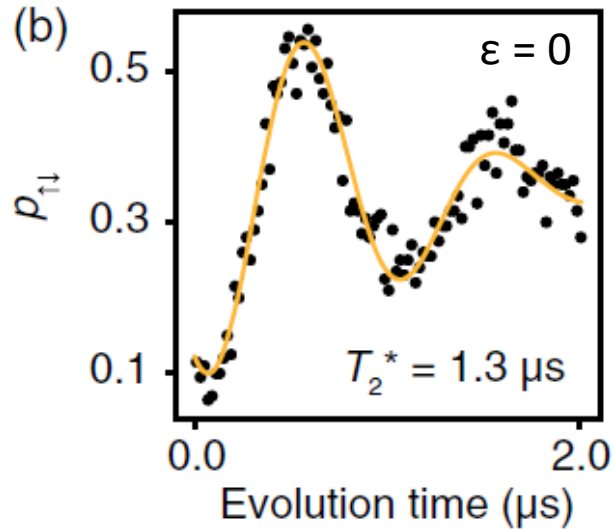
# Ramsey interferometry: Principle



# Ramsey interferometry: calculate $T_2^*$

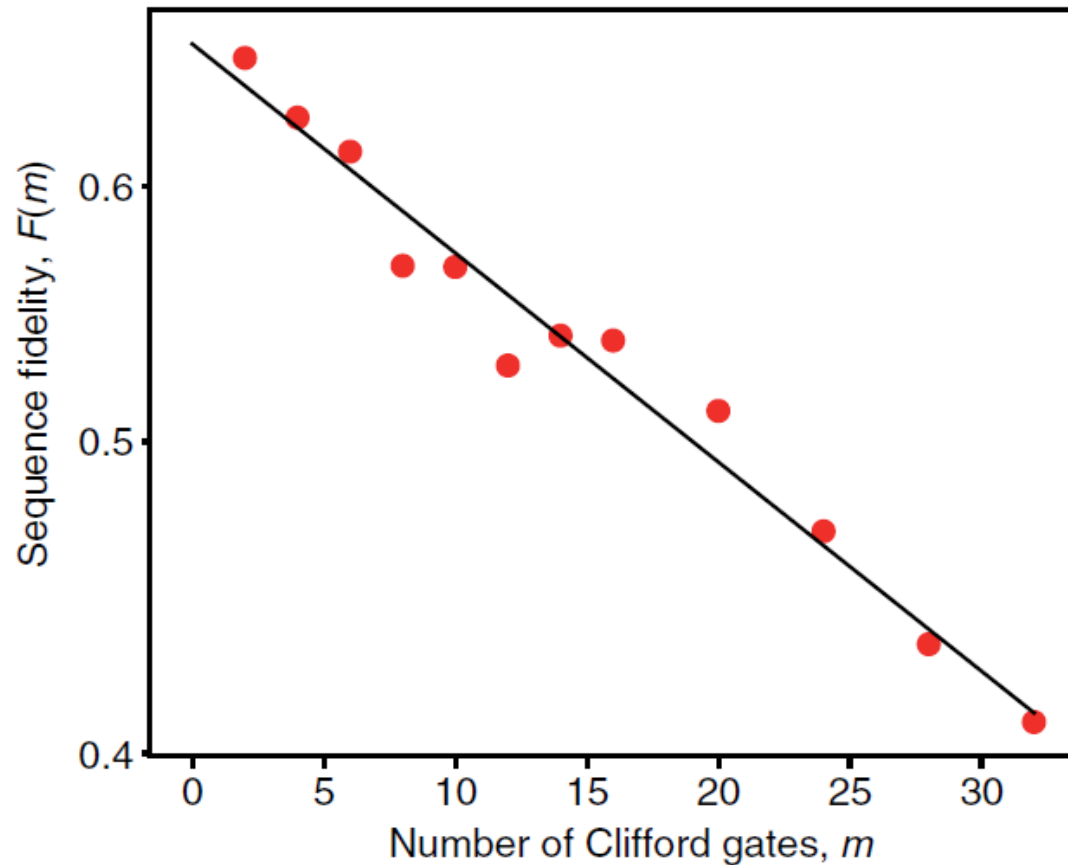
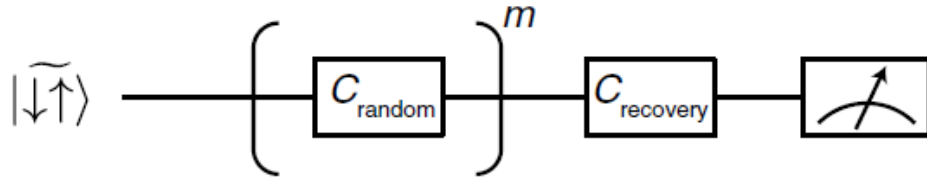


# Ramsey interferometry: $\varepsilon$ dependence of $T_2^*$



- $T_2^*$  is quite constant for  $-10 \text{ mV} \lesssim \varepsilon \lesssim 20 \text{ mV}$ .
- So, for other experiment they choose  $\varepsilon = 20 \text{ mV}$  ( $T_2^*$  still high but Rabi frequency twice faster than  $\varepsilon = 0$ )

# Fidelity benchmark



- Clifford gates are rotations in the Bloch Sphere. They are decomposed into rotations around the x and y axes (1.875 single gates on average)
- Fidelity  $F(m) = P_{|\downarrow\uparrow\rangle}(m) - P_{|\uparrow\downarrow\rangle}(m) = V p^m$
- From the fit:  **$p = 0.985 \pm 0.0009$**   
Clifford gate fidelity  $F_c = 99.2 \pm 0.045\%$   
Single gate fidelity  $F_{\text{single}} = 99.6 \pm 0.024\%$



# Conclusion

- Demonstration of the operation and fidelity benchmark of a resonantly driven singlet-triplet qubit in natural Si
- Good  $T_2^* \sim 1.3 \mu\text{s}$  for a natural Si made qubit
- Highest reported fidelity for “singlet-triplet spin qubit”

**Thank you for your attention!**

